

POSEICO SPA

Via N. Lorenzi 8, 16152 Genova - ITALY Tel. +39 010 6556234 - Fax +39 010 6557519

Sales Office:

Tel. +39 010 6556775 - Fax +39 010 6442510

FAST RECOVERY DIODE

ARF671

FOR IGBT,IEGT,GCT APPLICATIONS
SNUBBERLESS OPERATION
LOW LOSSES SOFT RECOVERY

Repetitive voltage up to Mean forward current Surge current

4500 V 790 A 15 kA

TARGET SPECIFICATION

giu 00 - ISSUE: 02

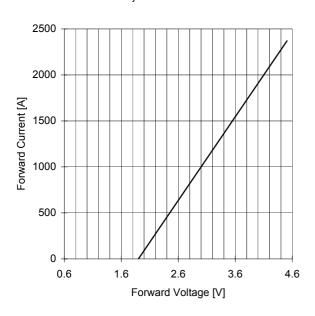
Symbol	Characteristic	Conditions	Tj [°C]	Value	Unit
BLOCK	KING				
V RRM	Repetitive peak reverse voltage		125	4500	V
V RSM	Non-repetitive peak reverse voltage		125	4600	V
I RRM	Repetitive peak reverse current	V=VRRM	125	80	mA
V DC LINK	Permanent DC voltage		125	2800	V
CONDU	JCTING				
I F (AV)	Mean forward current	180° sin ,50 Hz, Th=55°C, double side cooled		790	А
I F (AV)	Mean forward current	180° square,50 Hz,Th=55°C,double side cooled		820	Α
I FSM	Surge forward current	Sine wave, 10 ms reapplied reverse voltage up to 50% VRSM	125	15	kA
l² t	l² t			1125 x1E3	A²s
V FM	Forward voltage	Forward current = =2500 A	125	4.65	V
V F(TO)	Threshold voltage		125	1.90	V
rF	Forward slope resistance		125	1.100	mohm
SWITC	HING				
SWITC Q rr	Reverse recovery charge	I F = 1000 A di/dt= 250 A/µs	125	1000	μC
		I F = 1000 A di/dt= 250 A/μs VR = 100 V	125 125	1000 525	μC A
Q rr	Reverse recovery charge	<u> </u>			
Q rr I rr	Reverse recovery charge Peak reverse recovery current	VR = 100 V IF = 2100 A di/dt= 1000 A/μs			A
Q rr I rr t rr	Reverse recovery charge Peak reverse recovery current Reverse recovery time	VR = 100 V IF = 2100 A		525	Α μs
Q rr I rr t rr Q rr	Reverse recovery charge Peak reverse recovery current Reverse recovery time Reverse recovery charge	VR = 100 V IF = 2100 A di/dt= 1000 A/μs	125	525 2500	Α μs μC
Q m I m t m Q m I m	Reverse recovery charge Peak reverse recovery current Reverse recovery time Reverse recovery charge Peak reverse recovery current	VR = 100 V IF = 2100 A di/dt= 1000 A/μs	125	525 2500	Α μs μC
Q rr I rr Q rr I rr	Reverse recovery charge Peak reverse recovery current Reverse recovery time Reverse recovery charge Peak reverse recovery current Softness (s-factor), min	VR = 100 V IF = 2100 A di/dt= 1000 A/μs	125	525 2500	A μs μC A
Q rr I rr Q rr I rr s E OFF	Reverse recovery charge Peak reverse recovery current Reverse recovery time Reverse recovery charge Peak reverse recovery current Softness (s-factor), min Turn off energy dissipation Peak forward recovery	VR = 100 V IF = 2100 A di/dt= 1000 A/µs VR = 1800 V	125	525 2500	A μs μC A
Q m I m t m Q m I m s E OFF	Reverse recovery charge Peak reverse recovery current Reverse recovery time Reverse recovery charge Peak reverse recovery current Softness (s-factor), min Turn off energy dissipation Peak forward recovery	VR = 100 V IF = 2100 A di/dt= 1000 A/µs VR = 1800 V	125	525 2500	A μs μC A
Q rr I rr Q rr I rr s E OFF V FR	Reverse recovery charge Peak reverse recovery current Reverse recovery time Reverse recovery charge Peak reverse recovery current Softness (s-factor), min Turn off energy dissipation Peak forward recovery	VR = 100 V IF = 2100 A di/dt= 1000 A/μs VR = 1800 V di/dt= 400 A/μs	125	525 2500 1400	A μs μC A
Q rr I rr t rr Q rr I rr s E OFF V FR MOUNT	Reverse recovery charge Peak reverse recovery current Reverse recovery time Reverse recovery charge Peak reverse recovery current Softness (s-factor), min Turn off energy dissipation Peak forward recovery	VR = 100 V IF = 2100 A di/dt= 1000 A/μs VR = 1800 V di/dt= 400 A/μs Junction to heatsink, double side cooled	125	525 2500 1400	A μs μC A V
Q rr I rr t rr Q rr I rr s E OFF V FR MOUNT R th(j-h) R th(c-h)	Reverse recovery charge Peak reverse recovery current Reverse recovery time Reverse recovery charge Peak reverse recovery current Softness (s-factor), min Turn off energy dissipation Peak forward recovery TING Thermal impedance Thermal impedance	VR = 100 V IF = 2100 A di/dt= 1000 A/μs VR = 1800 V di/dt= 400 A/μs Junction to heatsink, double side cooled	125	525 2500 1400	A μs μC A V

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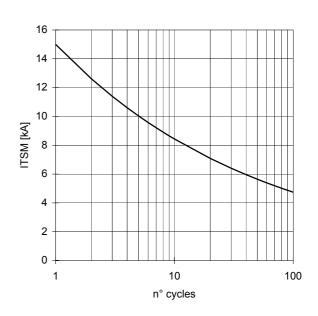


TARGET SPECIFICATION giu 00 - ISSUE: 02

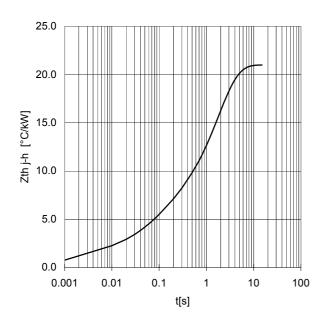
FORWARD CHARACTERISTIC Tj = 125 °C

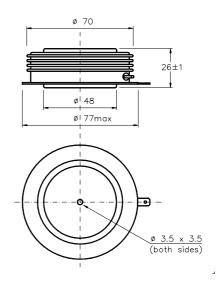


SURGE CHARACTERISTIC Tj = 125 °C



TRANSIENT THERMAL IMPEDANCE DOUBLE SIDE COOLED









All the characteristics given in this data sheet are guaranteed only with uniform clamping force, cleaned and lubricated heatsink, surfaces with flatness < .03 mm and roughness < 2 $\mu m.$

In the interest of product improvement ANSALDO reserves the right to change any data given in this data sheet at any time without previous notice.

If not stated otherwise the maximum value of ratings (simbols over shaded background) and characteristics is reported.

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